

DATE: 19th Sept, 2018

PCN #: 2366

PCN Title: Qualification of Additional Bill of Materials (BOM), Fab Source, AT Site and Top Marking Change on Select Product

Dear Customer:

This is an announcement of change(s) to products that are currently being offered by Diodes Incorporated.

We request that you acknowledge receipt of this notification within 30 days of the date of this PCN. If you require samples for evaluation purposes, please make a request within 30 days as well. Otherwise, samples may not be built prior to this change. Please refer to the implementation date of this change as it is stated in the attached PCN form. Please contact your local Diodes sales representative to acknowledge receipt of this PCN and for any sample requests.

The changes announced in this PCN will not be implemented earlier than 90 days from the notification date stated in the attached PCN form.

Previously agreed upon customer specific change process requirements or device specific requirements will be addressed separately.

For questions or clarification regarding this PCN, please contact your local Diodes sales representative.

Sincerely,

Diodes Incorporated PCN Team



PRODUCT CHANGE NOTICE

PCN-2366 REV 1

Notification Date:	Implementation Date:	ation Date: Product Family: Change Type: PCN #:						
19 th Sept, 2018	19 th Dec, 2018	Analog	BOM, Fab Source, A/T Site and Top Marking Change	2366				
		TITLE						
Qualification of Additi	Qualification of Additional Bill of Materials (BOM), Fab Source, A/T Site and Top Marking Change on Select Product							
	DESCRIPTION OF CHANGE							
additional bill of mate external FAB site (TP site Tianshui Huatian Full electrical characte change to product rel	This PCN is being issued to notify customers that in order to ensure continuity of supply Diodes Incorporated has qualified additional bill of material (BOM), and an additional Diodes internal Fab source (SFAB2) located in Shanghai, China, as well as external FAB site (TPSCo) TowerJazz Panasonic Semiconductor Co., Ltd. located in Hokuriku region of Japan, an additional A/T site Tianshui Huatian Technology Co (TSHT) located in Gansu, China, and Top Marking updates to reflect Diodes brand/logo. Full electrical characterization and reliability testing has been completed on representative part numbers to ensure there is no change to product reliability, device functionality or electrical specifications in the device datasheet. See attached qualification / reliability report (embedded in this file).							
		IMPACT						
No change in datash below.	eet electrical parameters	nowever, some devices will ha	ave different top marking as	noted in Tables 7 & 8				
		PRODUCTS AFFECTED						
Table 1 - Qualify Additional Fab Source (TPSCO)Table 2 -Qualify Additional Diodes Internal Fab Source SFAB2 (Shanghai, China) and Top Marking Change on Select ProductTable 3 - Top Marking Change Only on Select ProductTable 4 - Qualify Additional Top Metal (NiPt60%) Composition (Current is Pt100%) and Top Marking ChangeTable 5 - Qualify Additional A/T Site (TSHT)Table 6 - Qualify Additional Mold CompoundTable 7 - Top Marking by Packages SO-8, SOT26, SOIC-16Table 8 - Top Marking by Packages TSSOP-8, MSOP-8, SOT25, SOT353								
	WEB LINKS							
Manufacturer's Noti	ce: <u>https:/</u>	www.diodes.com/quality/produ	uct-change-notices/diodes-pr	oduct-change-notices/				
For More Informatio	n Contact: <u>http://v</u>	ww.diodes.com/contacts.html						
Data Sheet:	http://	ww.diodes.com/catalog						
		DISCLAIMER						
Unless a Diodes Incorporated Sales representative is contacted in writing within 30 days of the posting of this notice, all changes described in this announcement are considered approved.								



Table 1 - Qualify Additional Fab Source (TPSCO)					
AL3050FDC-7					

Table 2 - Qualify Additional FAB Source (SFAB2) and Top Marking Change					
AP4340NTR-G1	AP4340LNTR-G1	AZV321KSTR-G1	AZV321KTR-E1	AZV321KTR-G1	AZV358MTR-G1
AZV358GTR-E1	AZV358GTR-G1	AZV358MMTR-E1	AZV358MMTR-G1	AZV358MTR-E1	AP1681MTR-G1
AP3041MTR-G1	HL3051MTR-G1				

Table 3 – Top Marking Change Only					
AP2502KTR-G1	AP3031KTR-XG1	AP3031KTTR-G1	AP3602AKTR-G1	AP3064MTR-G1	

Table 4 - Qualify Additional Top Metal (NiPt60%) Composition (Current is Pt100%) and Top Marking Change					
AP3019AKTR-G1	AP3019AKTTR-G1	AP3019AUKTR-G1	AP3036BKTR-G1	AP3036KTR-G1	SP6699EK-L/TR
ZD1638LB6/TR-1					

Table 5 - Qualify Additional A/T Site (TSHT)					
AL8822SP-13	AL8823S-13				

Table 6 - Qualify Additional Mold Compound					
PI7C9X2G304SLBFDE	PI7C9X2G304SLBFDEX	PI7C9X2G304SLBQFDE	PI7C9X2G304SLBQFDEX	PI7C9X2G404SLBFDE	PI7C9X2G404SLBFDEX
PI7C9X2G404SLBQFDE	PI7C9X2G404SLBQFDEX	PI7C9X2G308GPANJE	PI7C9X2G308GPANJEX	PI7C9X2G312GPBNJE	PI7C9X2G312GPBNJEX
PI7C9X2G608GPBNJE	PI7C9X2G608GPBNJEX	PI7C9X2G612GPCNJE	PI7C9X2G612GPCNJEX	PI7C9X2G606PRDNJAE	PI7C9X2G606PRDNJAEX
PI7C9X2G912GPBNJEX	PI7C9X2G808PRBNJAEX				



Table 7





Table 8

Daskage		Side by Side com	parison Logo/Marking	
Package	Current BCD Top Marking		New Diodes Top Marking	
TSSOP-8		First Line: Logo Second Line: Marking ID Third and Fourth Lines: Date Code Y: Year WW: Work Weak of Molding A: Assembly House Code XX: Internal Code	MSOP-8 & TSSOP-8	
MSOP-8		First and Second Lines: Logo and Marking ID Third Line: Date Code Y: Year WW: Work Week Moding A: University Week Moding A: University Week A: Hermal Code	MSOP-8 (Top View)	
SOT25	5	View) 4	S0T25 and S0T353 (Top View) 5 4 XX : Identification Code Y. Year 0-9 XX Y WX Week; A+2; 1-25 week; a-2; 2-25 week; a-2; a-15 week 1 2 3	
SOT353	4	v • w • xxx Martingsito (See Ordering Information)		